

	Type	Hits	Search Text	DBs	Time Stamp	Comm ent s	Err or Def init on	Err ors	Ref #
1	BRS	13	250/492.21 and dielectric adj layer.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:34				S2
2	BRS	63	250/492.21 and dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:36				S1
3	BRS	32	250/492.21 and plasma adj immer\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:40				S3
4	BRS	4	Li-Hong-Jyh.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:42				S4
5	BRS	0	S4 and deposit near5 dielectric adj layer.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:43				S5

	Type	Hits	Search Text	DBs	Time Stamp	Comm ent s	Err or Def init on	Err ors	Ref #
6	BRS	0	S4 and implantation adj system near5 dielectric adj layer.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:43				S6
7	BRS	0	S4 and implantation adj system.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:43				S7
8	BRS	152	250/492.21 and implantation adj system.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:44				S9
9	BRS	0	S9 and DC adj voltage adj source.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:45				S11
10	BRS	0	S9 and AC adj voltage adj source.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:45				S12

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error #	Ref #
11	BRS	7	S9 and voltage adj source.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:45				S10
12	BRS	0	250/492.21 and implantation adj system near5 dielectric adj layer.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:46				S8
13	BRS	0	S14 and deposit near5 dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:48				S15
14	BRS	5	"250" and implantation adj system and dielectric adj layer.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:49				S14
15	BRS	0	"250" and implantation adj system and deposit near5 dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:49				S16

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error or Definition	Ref #
16	BRS	1	implantation adj system and deposit near5 dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:51			S17
17	BRS	0	implantation adj system and implant adj ions near5 dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:52			S18
18	BRS	12	implant adj ions near5 dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/14 14:52			S19
19	BRS	0	("6248662").URPN.	USPAT	2005/09/14 14:59			S20
20	BRS	1	("5489553").PN.	US-PGPUB; USPAT; USOCR	2005/09/14 14:59			S21
21	BRS	1	"6292150".pn.	US-PGPUB; USPAT; USOCR	2005/09/14 14:59			S22
22	BRS	0	250/492.21 and implantation adj system and dielectric adj layer.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 06:55			S13

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error #	Ref #
23	BRS	0	438/301 and implantation adj system and dielectric adj layer.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 06:56				S23
24	BRS	1	438/301 and implantation adj system and dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 06:57				S24
25	BRS	0	438/301 and implantation adj system and AC adj volt\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 06:58				S25
26	BRS	0	"438" and implantation adj system and AC adj volt\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 06:58				S26
27	BRS	6	"250" and implantation adj system and AC adj volt\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 07:04				S27

	Type	Hits	Search Text	DBs	Time Stamp	Comm ent s	Err or Def init on	Err ors	Ref #
28	BRS	116	"250" and ion adj implantation and AC adj volt\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 07:04				S28
29	BRS	58	S28 and DC adj volt\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 07:05				S29
30	BRS	35	S29 and plasma	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 07:06				S30
31	BRS	28	S30 and gas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:03				S31
32	BRS	3	S30 and dose and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:08				S33

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error or Definition	Ref #
33	BRS	13	implant adj ions near5 dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:12			S35
34	BRS	14	S29 and dose and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:13			S34
35	BRS	3	S35 and dose and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:13			S36
36	BRS	2	S31 and dose and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:16			S32
37	BRS	2	S31 and dose and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:16			S37

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error or Definition	Ref #
38	BRS	3	S30 and dos\$4 and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:17			S38
39	BRS	5	(US-20050136604-\$).did. or (US-6248662-\$ or US-6909087-\$ or US-6898065-\$ or US-6478924-\$).did.	US-PGPUB; USPAT	2005/09/15 08:19			S40
40	BRS	2	S40 and dos\$4 and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:22			S41
41	BRS	2	"6292150".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:24			S42
42	BRS	8	"10646533"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:48			S43
43	BRS	3067	"438" and buffer adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:48			S44



	Type	Hits	Search Text	DBs	Time Stamp	Co mm ent s	Err or Def init on	Err ors	Ref #
44	BRS	15	S29 and dos\$4 and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:49				S39
45	BRS	214	S44 and plasma and implant	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:49				S45
46	BRS	94	S45 and dos\$4 and energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:49				S46
47	BRS	30	S46 and dielectric adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/15 08:50				S47